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APPLICATION NO.	FILING DATE	, FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/764,528	01/27/2004	Hideyuki Kazumi	056204.53113US	9560
23911 75	7590 06/08/2006 EXAMINER			
0110 11 222 01	MORING LLP AL PROPERTY GROUP	ALEJANDRO M	ALEJANDRO MULERO, LUZ L	
P.O. BOX 14300			ART UNIT	PAPER NUMBER
WASHINGTO	WASHINGTON, DC 20044-4300			
			DATE MAILED: 06/08/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
Office Action Summany	10/764,528	KAZUMI ET AL.				
Office Action Summary	Examiner	Art Unit				
	Luz L. Alejandro	1763				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DATE - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period was really reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 6(a). In no event, however, may a reply be tim ill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONED	J. ely filed the mailing date of this communication. O (35 U.S.C. § 133).				
Status						
1)⊠ Responsive to communication(s) filed on 3/30/6	06.					
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3) Since this application is in condition for allowan	· · · · · · · · · · · · · · · · · · ·					
closed in accordance with the practice under E	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4)⊠ Claim(s) <u>1-12</u> is/are pending in the application.						
	vn from consideration					
 4a) Of the above claim(s) is/are withdrawn from consideration. 5) ☐ Claim(s) is/are allowed. 						
6)⊠ Claim(s) <u>1-12</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or	election requirement.	•				
Application Papers						
9)☐ The specification is objected to by the Examiner.						
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).						
11) ☐ The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form P1O-152.				
Priority under 35 U.S.C. § 119		· .				
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of:						
1. Certified copies of the priority documents						
2. Certified copies of the priority documents						
3. Copies of the certified copies of the priority documents have been received in this National Stage						
application from the International Bureau (PCT Rule 17.2(a)).						
* See the attached detailed Office action for a list of the certified copies not received.						
Attachment(s)						
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413)						
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail Da					

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-4 and 7-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ishii, U.S. Patent 5,571,366 in view of Masuda et al., US 2004/0045675 and Blalock, U.S. Patent 5,647,913.

Ishii shows the invention substantially as claimed including a plasma processing apparatus comprising: a vacuum reactor 2 having processing gas introduction means and evacuation means; a specimen placing device having an antenna electrode 63 for radiating high frequency power into the vacuum reactor, wherein first high frequency power is supplied to the antenna electrode, and an exciting coil 6 formed on an outer circumference of an outer circumferential wall of the vacuum reactor (see fig. 9 and its description).

Ishii does not expressly disclose a shield electrode formed on an outer circumferential wall of the vacuum reactor and where high frequency power at a frequency lower than that of the first high frequency power is supplied to the antenna electrode and shield electrode.

Masuda et al. discloses an antenna electrode having a first RF power supply 121 at a high frequency and a RF power supply 122 at a frequency lower than the first RF

power supply (see fig. 1 and paragraph 0051). Furthermore, Blalock discloses a shield electrode 26, wherein the shield electrode surrounds the vacuum reactor so as to control the voltage of the outer circumferential wall, the shield electrode having an RF power supply frequency 34 lower than the frequency supplied to the coil (see figs. 1-2 and their description). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the apparatus of Ishii so as to include the claimed antenna/shield electrode configuration as suggested by Masuda et al. and Blalock because in such a way the operation of the inductively coupled apparatus is optimized and undesired sputtering on the dielectric window can be reduced.

With respect to claims 3-4, note that the apparatus of Ishii modified by Masuda et al. and Blalock includes a slit formed at a portion of the shield electrode, facing the coil in a direction substantially perpendicular to the exciting coil, and an opening is formed at a central portion of the shield electrode on an upper surface of the vacuum reactor.

Concerning the disk-shaped cavity or disk-shaped dielectric layer, Ishii et al. discloses a dielectric layer 62 over the antenna electrode. It would have been obvious to one of ordinary skill in the art at the time the invention was made to determine through routine experimentation the optimum diameter of the disk-shaped cavity or disk-shaped dielectric layer depending upon a variety of factors including, for example, the anticipated amount of wear of the window and such limitation would not lend patentability to the instant invention absent a showing of unexpected results. Regarding the shape of the cavity or layer, the configuration of the claimed cavity or layer is a

matter of choice which a person of ordinary skill in the art would have found obvious absent persuasive evidence that the particular configuration of the claimed cavity or layer is significant.

Claims 5-6 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ishii, U.S. Patent 5,571,366 in view of Masuda et al., US 2004/0045675 and Blalock, U.S. Patent 5,647,913 as applied to claims 1-4 and 7-10 above, and further in view of Ye et al., U.S. Patent 5,710,486.

Ishii, Masuda, and Blalock et al. are applied as above but do not expressly disclose the antenna electrode and the shield electrode or the exciting coil connected by way of a power divider or a phase shifter. Ye discloses conductive elements such as electrodes and coils by way of power dividers and capacitors which can be used as phase shifters (see figs. 8-9 and their description). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the apparatus of Ishii modified by Masuda and Blalock so as to include power dividers and phase shifters in the claimed arrangement because in such a way the total number of power sources will be reduced.

Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ishii, U.S. Patent 5,571,366 in view of Masuda et al., US 2004/0045675 and Blalock, U.S.

Patent 5,647,913, as applied to claims 1-4 and 7-10 above, and further in view of Steger et al., U.S. Patent 5,788,799.

Ishii, Masuda et al., and Blalock are applied as above but do not expressly disclose a zirconium oxide film formed on an inner wall surface of the vacuum reactor. Steger et al. discloses a zirconium oxide film 102 formed on an inner wall surface of the vacuum reactor which can be composed of ceramics which are commonly dielectrics (see fig. 1 and its description and col. 5-lines 33-40). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the apparatus of Ishii modified by Masuda et al. and Blalock so as to include a zirconium oxide liner because in such a way the inner walls of the chamber will be protected.

Claim 12 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ishii, U.S. Patent 5,571,366 in view of Masuda et al., US 2004/0045675 and Blalock, U.S. Patent 5,647,913, as applied to claims 1-4 and 7-10 above, and further in view of Otsuki, US 2001/0003271.

Ishii, Masuda et al., and Blalock are applied as above but do not expressly disclose a vittrium oxide film on an inner wall surface of the vacuum reactor. Otsuki discsloses a vittrium oxide film 14 on an inner wall surface of a vacuum reactor (see fig. 1 and its description). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the apparatus of

Ishii modified by Masuda et al. and Blalock so as to form a yittrium oxide film on the inner walls of the vacuum reactor because this will provide a high corrosion resistance.

Response to Arguments

Applicant's arguments with respect to claims 1-12 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Luz L. Alejandro whose telephone number is 571-272-

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1430. The examiner can normally be reached on Monday to Thursday from 7:30 to

6:00.

273-8300.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Parviz Hassanzadeh can be reached on 571-272-1435. The fax phone number for the organization where this application or proceeding is assigned is 571-

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

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June 6, 2006